

# 150 Ampere STUD Power Diodes

### Features

- Alloy diode
- Popular series for rough service
- Stud cathode and stud anode version

### Typical Applications

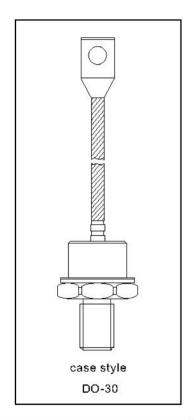
- Welders
- Power supplies
- Motor controls
- Battery chargers
- General industrial current rectification

### **ELECTRICAL SPECIFICATIONS**

I <sub>F(AV)</sub>	Maximum average forward current T <sub>o</sub> = 150°C	150 A
V <sub>FM</sub>	Maximum peak forward voltage drop @ Rated I <sub>F(peak)</sub>	1.33 V
  FSM	Maximum peak one cycle (non-rep.) surge current 10 msec.	3570 A
FRM	Maximum repetitive peak forward current	750 A
2 <b>t</b>	Max. I2t rating (non-rep.) 10 msec.	64000 A <sup>2</sup> Sec

### THERMAL MECHANICAL SPECIFICATIONS

θ <sub>J-C</sub>	Maximum thermal resistance junction to case	0.25° C/W
Өс-н	Contact thermal resistance	GD150N/R 0.07° C/W
Tj	Operating junction temp.	-40°C to 200°C
T <sub>slg</sub>	Storage temperature	-40°C to 200°C
W	Approx. weight	100 gms.



Mounting torque	minimum	7	Not lubricated threads	14.1 (125)	
GD150N/R	maximum		TVOCTUBITORION THERMAS	17.0 (150)	N→m
	minimum	Lubricated threads	Lubricated threads	12.2 (108)	(lbf · in)
	maximum		Labilitated tilleads	15.0 (132)	

### **ELECTRICAL RATINGS**

TYPE NUMBER GD150N/R		01	02	04	06	80	10	12	14	16
V <sub>RRM</sub> Max. repetitive peak reverse voltage (V)		100	200	400	600	800	1000	1200	1400	1600
V <sub>RSM</sub> Max. non-repetitive peak reverse voltage (V)		150	300	500	700	900	1100	1300	1500	1700
$V_{\text{R(RMS)}}$	Max. R.M.S. reverse voltage (V)	70	140	280	420	560	700	840	980	1120
V <sub>R</sub> Max. D.C. Blocking voltage (V)		100	200	400	600	800	1000	1200	1400	1600
Recommended R.M.S. working voltage (V)		40	80	160	240	320	400	480	560	640
$I_{RM}$ Max. Peak reverse leakage current @ $V_{RRM}$ , $T_{c}$ (mA)		15	15	15	12	9	7	7	6	5

1



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PARAMETER	SYMBOL		VALUES	UNITS		
Maximum average forward current	ximum average forward current I <sub>F(A)0</sub> 180° conduction, half sine wave				150	А
at case temperature	l <sub>F(AV)</sub>	160 CONQUE	ion, nan sine wav	150	°C	
Maximum RMS forward current	I <sub>F(RMS)</sub>	DC at 142 °C	case temperatur	re	235	A kA <sup>2</sup> s
		t = 10 ms	No voltage	Sinusoidal half wave, initial T <sub>J</sub> = T <sub>J</sub> maximum	3570	
Maximum peak, one cycle forward,	I <sub>FSM</sub>	t = 8.3 ms	reapplied		3740	
non-repetitive surge current		t = 10 ms	100 % V <sub>RRM</sub> reapplied		3000	
		t = 8.3 ms			3140	
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	t = 10 ms	No voltage reapplied		64	
		t = 8.3 ms			58	
		t = 10 ms	100 % V <sub>BRM</sub> reapplied		45	
		t = 8.3 ms			41	
Maximum I²√t for fusing	J²√t	t = 0.1 to 10 r	ns, no voltage re:	640	kA²√s	
Low level value of threshold voltage	V <sub>F(TO)1</sub>	(16.7 % x π x	$ I_{F(AV)} < I < \pi \times I_{F(AV)} $	0.67	V	
High level value of threshold voltage	V <sub>F(TO)2</sub>	$(I > \pi \times I_{F(AV)})$	ı, T <sub>J</sub> = T <sub>J</sub> maximu	0.83	"	
Low level value of forward slope resistance	r <sub>ff</sub>	(16.7% χπχ	$  F(AV)   <    < \pi \times   F  $	1.42	mΩ	
High level value of forward slope resistance	r <sub>f2</sub>	$(I > \pi \times I_{F(AV)})$	ı, T <sub>J</sub> = T <sub>J</sub> maximu	0.91		
Maximum forward voltage drop	$V_{\sf FM}$	I <sub>nk</sub> = 471 A, T	J = 25 °C, t <sub>p</sub> = 10	1.33	V	

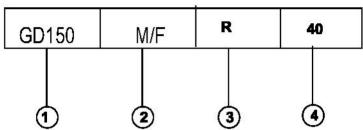
∆R <sub>thJC</sub> CONDUCTION							
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS			
180°	0.031	0.023					
120°	0.038	0.040	$T_J = T_J \text{ maximum}$	K/W			
90°	0.048	0.053					
60°	0.071	0.075					
30°	0.120	0.121	1				

### Note

• The table above shows the increment of thermal resistance RthJC when devices operate at different conduction angles than DC

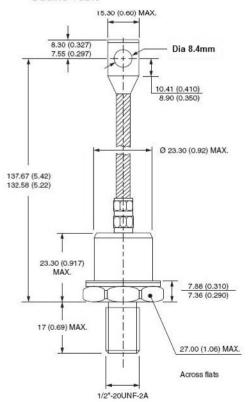


# **ORDER INFORMATION TABLE**



- (1) GD150 Essential Part no.
- One Stud with 1/2" 20 UNF-2A Threading
  M Stud with M12 Threading
- N Normal polarity
   R Reverse polarity
- (4) Voltage Rating (See table)

#### Outline Table



## **POLARITY**



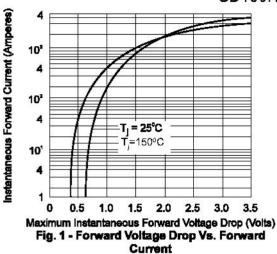


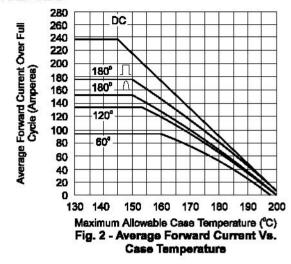
R= Reverse polarity Cathode base N= Normal polarity Anode base

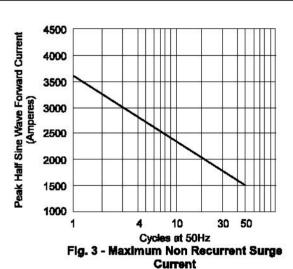
Conforms to JEDEC (30mm2 braid) DO-30 All dimensions in millimeters (inches)

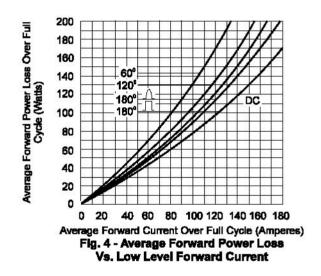


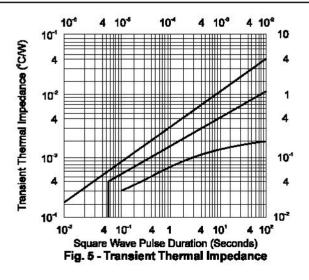
# GD150N/R-XX..SERIES

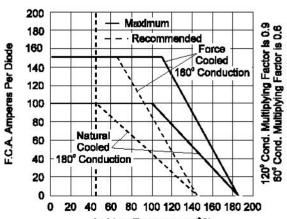












Ambient Temperature (°C)
Fig. 6 - Diode GD150N/R Mounted on Heat Sink
Type K5 with 9HA-NC 0.55° C/W FC 0 13°C/W

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